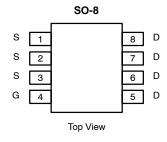




N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(\Omega)$	I _D (A)	
30	0.0045 @ V _{GS} = 10 V	20	
	0.0055 @ V _{GS} = 4.5 V	19	



Ordering Information: Si4362DY

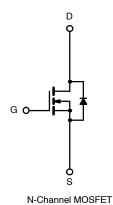
SI4302D1 Si4362DY-T1 (with Tape and Reel) Si4362DY-E3 (Lead Free) Si4362DY-T1—E3 (Lead Free with Tape and Reel)

FEATURES

- TrenchFET® Power MOSFET
- Optimized for "Low Side" Synchronous Rectifier Operation
- 100% R_g Tested

APPLICATIONS

- DC/DC Converters
- Synchronous Rectifiers



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED) ^a					
Parameter		Symbol	Limits	Unit	
Drain-Source Voltage		V _{DS}	30		
Gate-Source Voltage		V _{GS}	±12		
Continuos Duris Courset (T., 45000)8	T _A = 25°C		20		
Continuous Drain Current (T _J = 150°C) ^a	T _A = 70°C	'D	15		
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	60	A	
Continuous Source Current (Diode Conduction) ^a		I _S	2.9		
Mandanian Davis Director Atlanta	T _A = 25°C	Б	3.5	10/	
Maximum Power Dissipation ^a	T _A = 70°C	P _D	2.2	— w	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150		

THERMAL RESISTANCE RATINGS ²					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient	R _{thJA}	29	35	0000	
Maximum Junction-to-Foot (Drain)	R_{thJF}	13	16	°C/W	

Notes

a. Surface Mounted on 1" x 1" FR4 Board, $t \le 10$ sec

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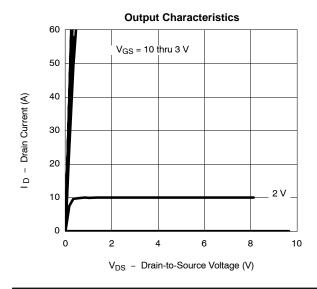


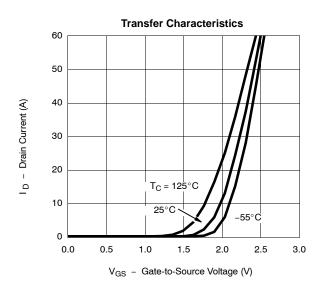
SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit		
Static	•		•	•	•	•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.6			V		
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = \pm 12 V			±100	nA		
7 O-t- Vallana Dunia Onnort		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	1.		
Zero Gate Voltage Drain Current	DSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	μA		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = 10 V, I _D = 20 A		0.0035	0.0045	0		
Drain-Source On-State Resistance		$V_{GS} = 4.5 \text{ V}, I_D = 19 \text{ A}$		0.0042	0.0055	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		90		S		
Diode Forward Voltage ^a	V _{SD}	$I_S = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.1	V		
Dynamic ^b								
Total Gate Charge	Q_g			42	55	nC		
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 20 A		12.8				
Gate-Drain Charge	Q _{gd}			7.7				
Gate Resistance	R _G		0.5	1.3	2.2	Ω		
Turn-On Delay Time	t _{d(on)}			17	30	ns		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		14	25			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		158	230			
Fall Time	t _f			43	65			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, di/dt = 100 A/μs		50	80			

Notes

- a. Pulse test; pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$. b. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

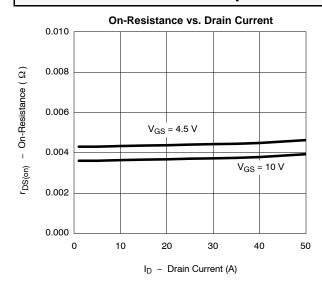


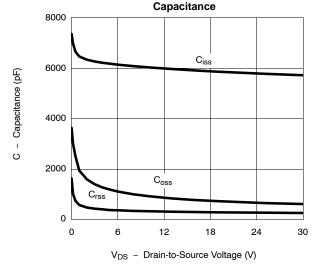


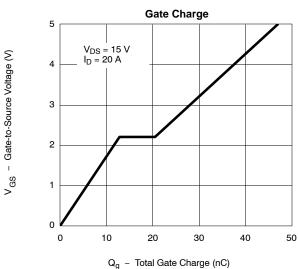


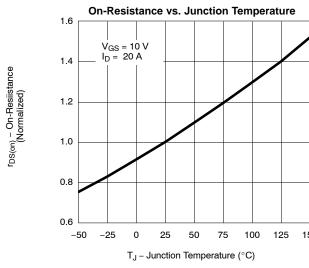
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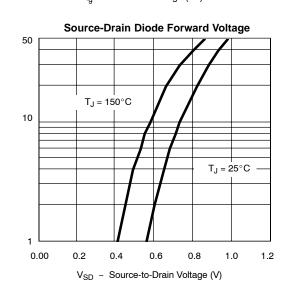
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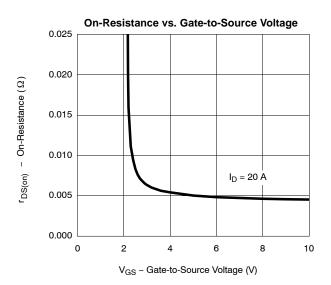










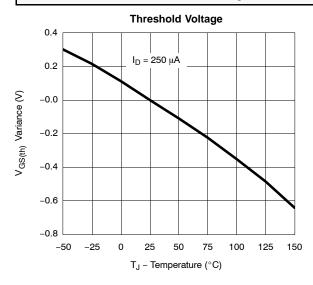


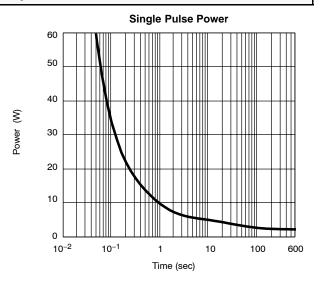
- Source Current (A)

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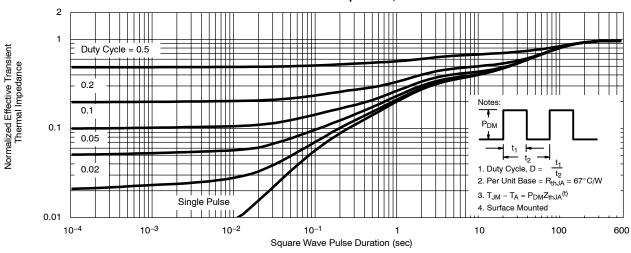


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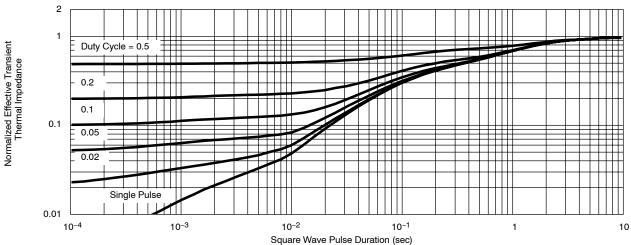




Normalized Thermal Transient Impedance, Junction-to-Ambient







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